

## **Product Summary**

BV <sub>DSS</sub>	Rds(on)	ID TA = +25°C
450V	50Ω @ V <sub>GS</sub> = 10V	140mA

## **Description and Applications**

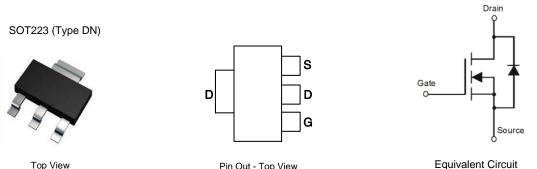
This MOSFET is designed to minimize the on-state resistance yet maintain superior switching performance, making it ideal for high efficiency power management applications.

## **Features and Benefits**

- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. https://www.diodes.com/guality/product-definitions/

## **Mechanical Data**

- Package: SOT223
- Package Material: Molded Plastic, UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.112 grams (Approximate)



Top View

## Ordering Information (Note 4)

Part Number	Backago	Pa	Packing		
	Package	Qty.	Carrier		
ZVN0545GTA	SOT223 (Type DN)	1,000	Tape & Reel		

Pin Out - Top View

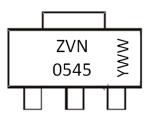
1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## **Marking Information**

Notes:



ZVN0545 = Product Type Marking Code YWW = Date Code Marking Y or  $\overline{Y}$  = Last Digit of Year (ex. 1 = 2021) WW or  $\overline{W}W$  = Week Code (01 to 53)



# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Drain-Source Voltage		VDSS	450	V
Gate-Source Voltage		Vgss	±20	V
Continuous Drain Current V <sub>GS</sub> = 10V	T <sub>A</sub> = +25°C	lo	140	mA
Pulsed Drain Current		Ідм	600	mA

# Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation	T <sub>A</sub> = +25°C	PD	2	W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage	BVDSS	450	_	—	V	$V_{GS} = 0V, I_D = 1mA$	
Zero Gate Voltage Drain Current	Inco	_	_	10	μA	$V_{DS} = 450 V, V_{GS} = 0 V$	
Zero Gale Voltage Drain Current	IDSS			400	μA	V <sub>DS</sub> =405V, V <sub>GS</sub> =0V, T=+125°C (Note 6)	
Gate-Source Leakage	IGSS		_	±20	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS							
Gate Threshold Voltage	Vgs(th)	1	—	3	V	$V_{DS} = V_{GS}, I_D = 1mA$	
Static Drain-Source On-State Resistance (Note 5)	RDS(ON)		_	50	Ω	$V_{GS} = 10V, I_{D} = 100mA$	
On-State Drain Current (Note 5)	ID(ON)	150	—	—	mA	V <sub>DS</sub> =25V, V <sub>GS</sub> =10V	
Forward Transconductance (Notes 5 and 6)	<b>g</b> fs	100	_	_	mS	V <sub>DS</sub> =25V,I <sub>D</sub> =100mA	
DYNAMIC CHARACTERISTICS (Note 6)							
Input Capacitance	Ciss	—	—	70	pF		
Output Capacitance	Coss		_	10	pF	$V_{DS} = 25V, V_{GS} = 0V, f = 1MHz$	
Reverse Transfer Capacitance	Crss	—	—	4	pF	1	
Turn-On Delay Time (Note 7)	t <sub>D(ON)</sub>		_	7	ns		
Turn-On Rise Time (Note 7)	tR			7	ns		
Turn-Off Delay Time (Note 7)	tD(OFF)			16	ns	$V_{DD} = 25V, I_{D} = 100 \text{mA}$	
Turn-Off Fall Time (Note 7)	tF			10	ns	1	

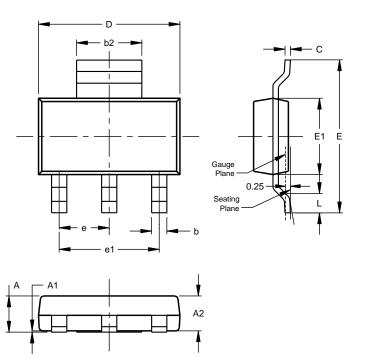
Notes: 5. Measured under pulsed conditions. Width=300 $\mu$ s. Duty cycle ≤ 2%.

6. Sample test. 7. Switching times measured with 50Ω source impedance and <5ns rise time on a pulse generator.



## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.



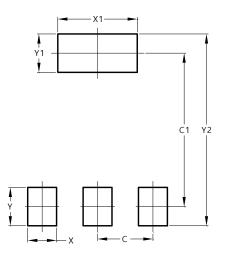
r					
SOT223 (Type DN)					
Dim	Min	Max	Тур		
Α		1.70			
A1	0.01	0.15			
A2	1.50	1.68	1.60		
b	0.60	0.80	0.70		
b2	2.90	3.10			
С	0.20	0.32			
D	6.30	6.70			
E	6.70	7.30			
E1	3.30	3.70			
е			2.30		
e1			4.60		
L	0.85				
All Dimensions in mm					

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### SOT223 (Type DN)

SOT223 (Type DN)



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00



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